



INTERNATIONAL
GEMOLOGICAL
INSTITUTE

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LABORATORY GROWN DIAMOND REPORT

July 24, 2024

IGI Report Number

DESCRIPTION

SHAPE AND CUTTING STYLE

MEASUREMENTS

GRADING RESULTS

CARAT WEIGHT

COLOR GRADE

CLARITY GRADE

ADDITIONAL GRADING INFORMATION

POLISH

SYMMETRY

FLUORESCENCE

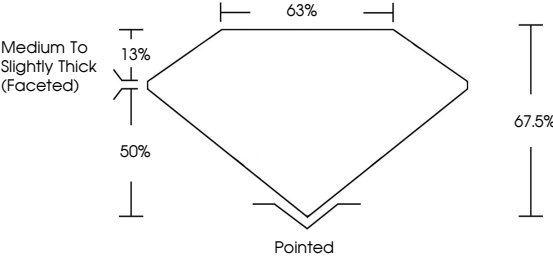
INSCRIPTION(S)

COMMENTS: This Laboratory Grown Diamond was created by Chemical Vapor Deposition (CVD) growth process. Type IIa

LG645456614

Report verification at [igi.org](#)

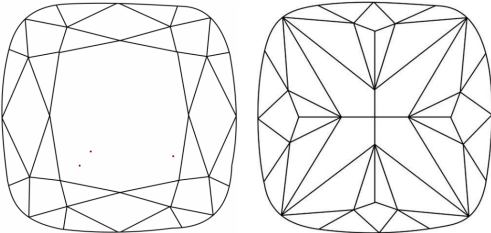
PROPORTIONS





Sample Image Used

CLARITY CHARACTERISTICS



KEY TO SYMBOLS

Red symbols indicate internal characteristics.
Green symbols indicate external characteristics.

COLOR

D E F G H I J Faint Very Light Light

CLARITY

IF VS 1-2 VS 1-2 SI 1-2 I 1-3

Internally Flawless Very Very Slightly Included Very Slightly Included Slightly Included Included

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Description

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GRADING RESULTS

Carat Weight

Color Grade

Clarity Grade

ADDITIONAL GRADING INFORMATION

Polish

Symmetry

Fluorescence

Inscription(s)

COMMENTS: This Laboratory Grown Diamond was created by Chemical Vapor Deposition (CVD) growth process. Type IIa

LG645456614

LABORATORY GROWN DIAMOND

SQUARE CUSHION BRILLIANT

5.89 X 5.76 X 3.89 MM

1.03 CARAT

D

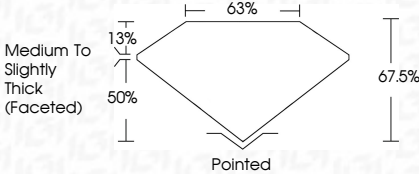
VVS 2

EXCELLENT

EXCELLENT

NONE

IGI LG645456614





IGI

July 24, 2024

IGI Report No LG645456614

SQUARE CUSHION BRILLIANT

5.89 X 5.76 X 3.89 MM

1.03 CARAT

D

VVS 2

67.5%

63%

Medium to Slightly Thick (Faceted)

Pointed

EXCELLENT

EXCELLENT

NONE

IGI LG645456614

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